## **EAST Search History**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	188	koo near2 jae-bon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/15 16:17
L2	26	l1 and (park near2 ji-yong)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/15 16:22
13	11943	257/59:ccls. or 257/72:ccls. or 257/64:ccls. or 257/88:ccls. or 257/89:ccls. or 257/90:ccls. or 257/91:ccls. or 257/92:ccls. or 257/93:ccls. or 257/E21:134:ccls. or 257/E27:111:ccls. or 257/E29: 003:ccls. or 257/E29:024:ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/15 16:24
L4	855	(257/59.ccls. or 257/72.ccls. or 257/64.ccls. or 257/88.ccls. or 257/89.ccls. or 257/90.ccls. or 257/91.ccls. or 257/92.ccls. or 257/93.ccls. or 257/E21.134.ccls. or 257/E27.111.ccls. or 257/E29. 003.ccls. or 257/E29.024.ccls.) and ((tft or (thin near film near transistor)) same channel same polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/15 16:26
L5	274	(257/59.ccls. or 257/72.ccls. or 257/64.ccls. or 257/88.ccls. or 257/89.ccls. or 257/90.ccls. or 257/91.ccls. or 257/92.ccls. or 257/93.ccls. or 257/E21.134.ccls. or 257/E27.111.ccls. or 257/E29. 003.ccls. or 257/E29.024.ccls.) and ((tft or (thin near film near transistor)) same channel same polysilicon same (thick or thickness or thicker or grain))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/15 16:25
L6	1486	(257/59.ccls. or 257/72.ccls. or 257/64.ccls. or 257/88.ccls. or 257/89.ccls. or 257/90.ccls. or 257/91.ccls. or 257/92.ccls. or 257/93.ccls. or 257/E21.134.ccls. or 257/E27.111.ccls. or 257/E29. 003.ccls. or 257/E29.024.ccls.) and ((tft or (thin near film near transistor)) same channel same (polysilicon or (polycrystalline near silicon)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/15 16:28

## **EAST Search History**

L7	486	257/64.ccls. or 257/88.ccls. or 257/89.ccls. or 257/90.ccls. or 257/91.ccls. or 257/92.ccls. or 257/93.ccls. or 257/E21.134.ccls. or 257/E27.111.ccls. or 257/E29. 003.ccls. or 257/E29.024.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/15 16:28
		and ((tft or (thin near film near transistor)) same channel same (switch or switching or driving or driver) same (polysilicon or (polycrystalline near silicon)))				

1/15/08 4:29:13 PM
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